

ABSTRACT OF DISCLOSURE

A method for generating an initializing signal capable of preventing inner circuits installed in a semiconductor memory device from being initially unstably operated due to the application of external electric power. The method includes the steps of: (a) receiving a precharge command for precharging the semiconductor memory device; (b) activating the initializing signal to a first level in response to the received precharge command; (c) receiving a refresh command for refreshing the semiconductor memory device after receipt of the precharge command; (d) receiving a mode set command for setting an operational mode of the semiconductor memory device after receipt of the refresh command; and (e) deactivating the initializing signal to a second level in response to the received mode set command. An alternative method includes the step of (a) receiving a mode set command for initializing an inner circuit in a semiconductor memory device and (b) generating a control signal in response to the received mode set command and using the control signal as the initializing signal.